

# 6 + 6W STEREO AMPLIFIER WITH MUTE & ST-BY

- WIDE SUPPLY VOLTAGE RANGE UP TO ±18V
- 6 + 6W @ THD = 10%,  $R_L = 8\Omega$ ,  $V_S = \pm 14V$
- NO POP AT TURN-ON/OFF
- MUTE (POP FREE)
- STAND-BY FEATURE (LOW I<sub>a</sub>)
- SHORT CIRCUIT PROTECTION TO GND
- THERMAL OVERLOAD PROTECTION

#### **DESCRIPTION**

The TDA7499 is class AB dual Audio power amplifier assembled in the Multiwatt package, specially designed for high quality sound application as Hi-Fi music centers and stereo TV sets.

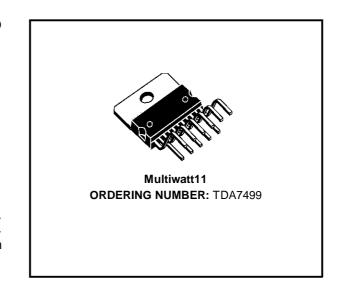
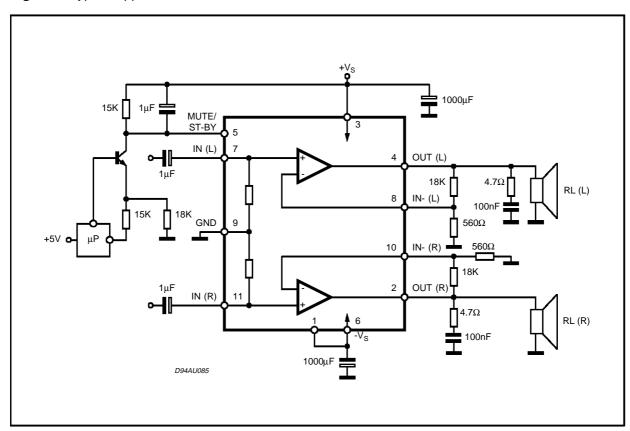


Figure 1: Typical Application Circuit

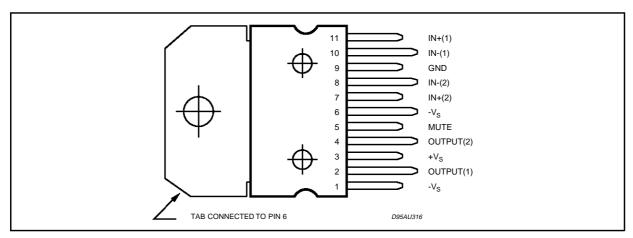


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#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
Vs	DC Supply Voltage	±20	V
lo	Output Peak Current (internally limited)	2.5	Α
P <sub>tot</sub>	Power Dissipation T <sub>case</sub> = 70°C	23	W
T <sub>op</sub>	Operating Temperature	0 to 70	°C
T <sub>stg</sub> , T <sub>j</sub>	Storage and Junction Temperature	-40 to +150	°C

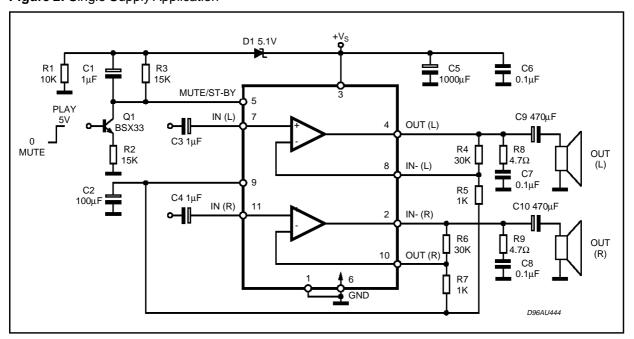
### **PIN CONNECTION** (Top view)



#### **THERMAL DATA**

Symbol	Description			Unit
R <sub>th j-case</sub>	Thermal Resistance Junction-case	Max	2.8	°C/W
R <sub>th j-amb</sub>	Thermal Resistance Junction to Ambient	Max	35	°C/W

Figure 2: Single Supply Application



# **ELECTRICAL CHARACTERISTICS** (Refer to the test circuit, $V_S = \pm 14V$ ; $R_S = 50\Omega$ ; $G_V = 30dB$ ; f = 1KHz; $T_{amb} = 25^{\circ}C$ , unless otherwise specified.)

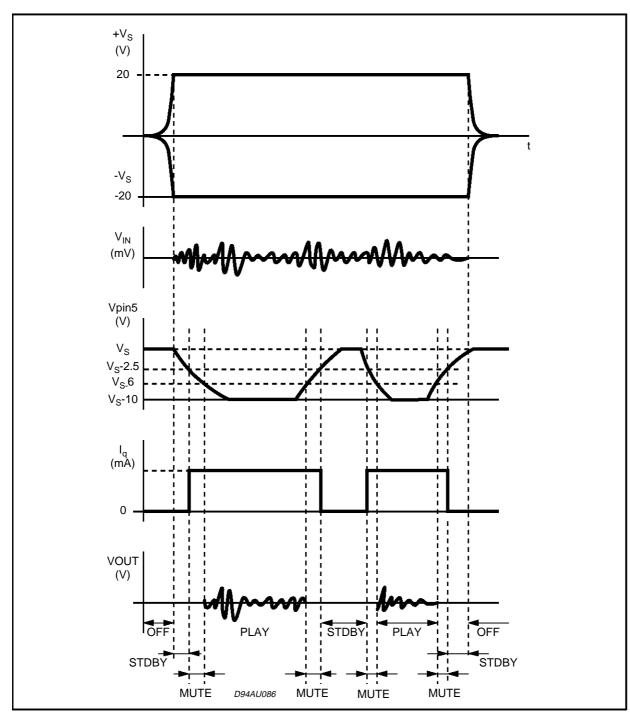
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vs	Supply Range	$R_L = 8\Omega$	<u>+</u> 5		<u>+</u> 18	V
		$R_L = 4\Omega$	<u>+</u> 5		<u>+</u> 13.5	V
Iq	Total Quiescent Current			50	90	mΑ
Vos	Input Offset Voltage		-25		+25	mV
I <sub>b</sub>	Output Bias Current			500		nA
Po	Output Power	THD = 10% $R_L = 8\Omega$ ; $V_S \pm 11V$ ; $R_L = 4\Omega$	8	10 7.5		W W
		THD = 1% $R_L = 8\Omega$ ; $V_S \pm 11V$ ; $R_L = 4\Omega$	6	7.5 6		W W
THD	Total Harmonic Distortion	$R_L = 8\Omega$ ; $P_O = 1W$ ; $f = 1KHz$		0.03		%
		$R_L = 8\Omega$ ; $P_O = 0.1$ to 5W; $V_S \pm 13V$ ; f = 100Hz to 15KHz		0.2	0.5	%
		$R_L = 4\Omega$ ; $P_O = 1W$ ; $f = 1KHz$		0.02		%
		$R_L = 4\Omega$ ; $V_S \pm 10V$ ; $P_O = 0.1$ to $4W$ ; f = 100Hz to $15$ KHz		0.2	1	%
Ст	Cross Talk	f = 1KHz f = 10KHz	50	70 60		dB dB
SR	Slew Rate		6.5	10		V/μs
G <sub>OL</sub>	Open Loop Voltage Gain			80		dB
e <sub>N</sub>	Total Input Noise	A Curve f = 20Hz to 22KHz		3 4	8	μV μV
Ri	Input Resistance		15	20		ΚΩ
SVR	Supply Voltage Rejection (each channel)	fr = 100Hz Vr = 0.5V		60		dB
Tj	Thermal Shut-down Junction Temperature			145		°C
MUTE FUN	CTION [ref: +Vs]					
VT <sub>MUTE</sub>	Mute / Play Threshold		-7	-6	-5	V
A <sub>M</sub>	Mute Attenuation		60	70		dB
STAND-BY	FUNCTION [ref: +Vs] (only For S	plit Supply)				
VT <sub>ST-BY</sub>	Stand-by / Mute Threshold		-3.5	-2.5	5	V
A <sub>ST-BY</sub>	Stand-by Attenuation			110		dB
I <sub>q ST-BY</sub>	Quiescent Current @ Stand-by			3	6	mA

#### **MUTE STAND-BY FUNCTION**

The pin 5 (MUTE/STAND-BY) controls the amplifier status by two different thresholds, referred to  $\pm V_S$ .

- When  $V_{pin5}$  higher than = +Vs 2.5V the amplifier is in Stand-by mode and the final stage generators are off
- when V<sub>pin5</sub> is between +Vs 2.5V and +Vs
   6V the final stage current generators are switched on and the amplifier is in mute mode
- when V<sub>pin5</sub> is lower than +Vs 6V the amplifier is play mode.

Figure 3.



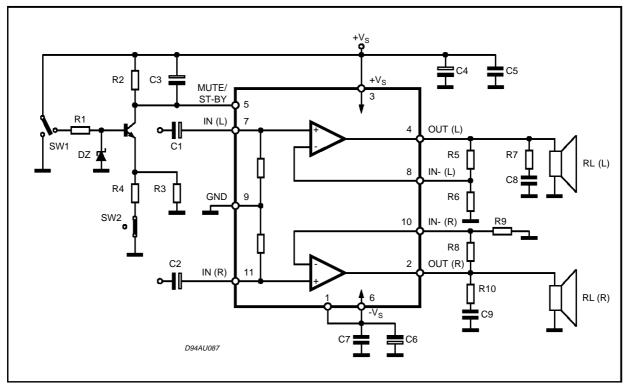


Figure 4: Test and Application Circuit (Stereo Configuration).

### **APPLICATIONS SUGGESTION**

(Demo Board Schematic)

The recommended values of the external compo-

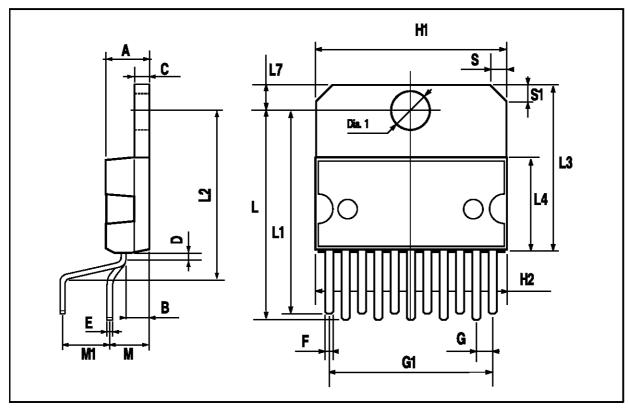
nents are those shown are the demo board schematic different values can be used: the following table can help the designer.

COMPONENTS	RECOMMENDED VALUE	PURPOSE	LARGER THAN RECOMMENDED VALUE	SMALLER THAN RECOMMENDED VALUE
R1	10ΚΩ	Mute Circuit	Increase of Dz Biasing Current	
R2	15ΚΩ	Mute Circuit	V <sub>pin</sub> # 5 Shifted Downward	V <sub>pin</sub> # 5 Shifted Upward
R3	18ΚΩ	Mute Circuit	V <sub>pin</sub> # 5 Shifted Upward	V <sub>pin</sub> # 5 Shifted Downward
R4	15KΩ	Mute Circuit	V <sub>pin</sub> # 5 Shifted Upward	V <sub>pin</sub> # 5 Shifted Downward
R5, R8 18KΩ		Closed Loop Gain	Increase of Gain	
R6, R9	560Ω	Setting (*)	Decrease of Gain	
R7, R10	4.7Ω	Frequency Stability	Danger of Oscillations	Danger of Oscillations
C1, C2	1μF	Input DC Decoupling		Higher Low Frequency Cutoff
C3	1μF	St-By/Mute Time Constant	Larger On/Off Time	Smaller On/Off Time
C4, C6	1000μF	Supply Voltage Bypass		Danger of Oscillations
C5, C7	0.1μF	Supply Voltage Bypass		Danger of Oscillations
C8, C9	0.1μF	Frequency Stability		
Dz	5.1V	Mute Circuit		

<sup>(\*)</sup> Closed loop gain has to be => 25dB

## **MULTIWATT11 PACKAGE MECHANICAL DATA**

DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Α			5			0.197	
В			2.65			0.104	
С			1.6			0.063	
D		1			0.039		
Е	0.49		0.55	0.019		0.022	
F	0.88		0.95	0.035		0.037	
G	1.57	1.7	1.83	0.062	0.067	0.072	
G1	16.87	17	17.13	0.664	0.669	0.674	
H1	19.6			0.772			
H2			20.2			0.795	
L	21.5		22.3	0.846		0.878	
L1	21.4		22.2	0.843		0.874	
L2	17.4		18.1	0.685		0.713	
L3	17.25	17.5	17.75	0.679	0.689	0.699	
L4	10.3	10.7	10.9	0.406	0.421	0.429	
L7	2.65		2.9	0.104		0.114	
М	4.1	4.3	4.5	0.161	0.169	0.177	
M1	4.88	5.08	5.3	0.192	0.200	0.209	
S	1.9		2.6	0.075		0.102	
S1	1.9		2.6	0.075		0.102	
Dia1	3.65		3.85	0.144		0.152	



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